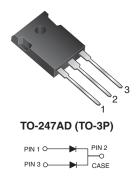


MBR30H90PT, MBR30H100PT

Vishay General Semiconductor

Dual Common Cathode High Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



| PRIMARY CHARACTERISTICS | | | | | |
|-------------------------|------------------|--|--|--|--|
| I _{F(AV)} | 2 x 15 A | | | | |
| V _{RRM} | 90 V, 100 V | | | | |
| I _{FSM} | 265 A | | | | |
| V _F | 0.67 V | | | | |
| I _R | 5.0 µA | | | | |
| T _J max. | 175 °C | | | | |
| Package | TO-247AD (TO-3P) | | | | |
| Diode variations | Common cathode | | | | |

FEATURES

- Power pack
- Guardring for overvoltage protection
- · Lower power losses, high efficiency
- Low forward voltage drop
- Low leakage current
- · High forward surge capability
- High frequency operation
- Solder dip 275 °C max., 10 s, per JESD 22-B106
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

MECHANICAL DATA

Case: TO-247AD (TO-3P)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted) | | | | | |
|---|--------------|-----------------------------------|------------------------|-----|------|
| PARAMETER | | SYMBOL | MBR30H90PT MBR30H100PT | | UNIT |
| Maximum repetitive peak reverse voltage | | V _{RRM} | 90 | 100 | V |
| Working peak reverse voltage | | V _{RWM} | 90 | 100 | V |
| Maximum DC blocking voltage | | V _{DC} | 90 | 100 | V |
| Maximum average forward rectified current | total device | | 30 | | А |
| | per diode | I _{F(AV)} | 15 | | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | | I _{FSM} | 265 | | А |
| Peak repetitive reverse surge current at $t_p = 2 \ \mu s$, 1 kHz per diode | | I _{RRM} | 1.0 | | А |
| Non-repetitve avalanche energy ($I_{AS} = 0.5 \text{ A}, L = 60 \text{ mH}$) per diode | | E _{AS} | 7.5 | | mJ |
| Voltage rate of change (rated V _R) | | dV/dt | 10 000 | | V/µs |
| Operating junction and storage temperature range | | T _J , T _{STG} | -65 to +175 | | °C |





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| ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted) | | | | | | |
|---|-------------------------------|-----------------------|-------------------------|------------|-------------|------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MBR30H90PT | MBR30H100PT | UNIT |
| Maximum instantaneous forward voltage per diode | V _F ⁽¹⁾ | I _F = 15 A | T _J = 25 °C | 0.82 | | V |
| | | I _F = 15 A | T _J = 125 °C | 0.67 | | |
| | | I _F = 30 A | T _J = 25 °C | 0. | 93 | V |
| | | I _F = 30 A | T _J = 125 °C | 0. | 80 | |
| Maximum instantaneous reverse current at rated DC blocking voltage per diode | I _R ⁽¹⁾ | | T _J = 25 °C | 5 | .0 | μA |
| | | | T _J = 125 °C | 6 | .0 | mA |

Note

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

| THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted) | | | | | | |
|--|---------------------|------------------------|--|------|--|--|
| PARAMETER | SYMBOL | MBR30H90PT MBR30H100PT | | UNIT | | |
| Thermal resistance, junction to case per diode | $R_{	ext{	heta}JC}$ | 1.6 | | °C/W | | |

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|-------------------|-----------------|--------------|---------------|---------------|--|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | | |
| TO-247AD | MBR30H100PT-E3/4W | 6.13 | 45 | 30/tube | Tube | | |

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

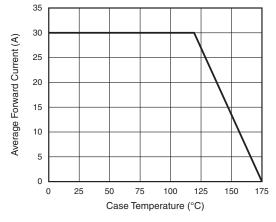


Fig. 1 - Forward Derating Curve

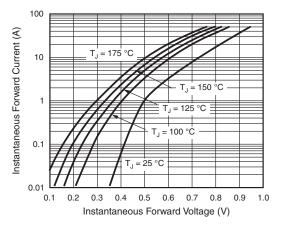


Fig. 2 - Typical Instantaneous Forward Characteristics Per Diode



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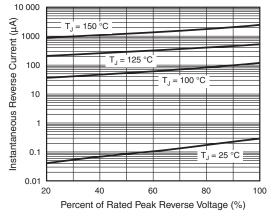


Fig. 3 - Typical Reverse Characteristics Per Diode

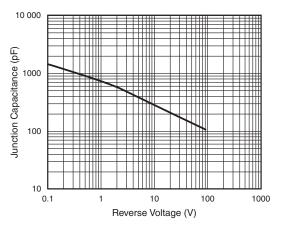
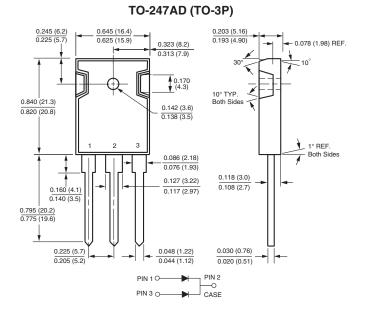


Fig. 4 - Typical Junction Capacitance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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